# NSN 5961-01-353-5522

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-353-5522

Inclosure Material:

Plastic

**Overall Length:** 

0.115 inches

# **Overall Height:**

0.145 inches

Overall Width:

0.188 inches

## Internal Configuration:

Junction contact

# Mounting Method:

Terminal

Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

15.0 collector to emitter voltage/static/base open and 40.0 collector to emitter voltage, dc with base short-circuited to emitter and 40.0 collector to base voltage/static/emitter open and 4.5 emitter to base voltage, static, collector open

### **Current Rating Per Characteristic:**

500.00 milliamperes source cutoff current

## **Power Rating Per Characteristic:**

225.0 milliwatts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

### Terminal Type And Quantity:

3 ribbon

Shelf Life:

N/a

### Unit Of Measure:

---

### Demilitarization:

No

## Fiig:

A110a0